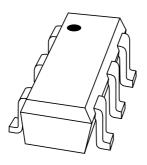
#### **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# BC847BPN NPN/PNP general purpose transistor

Product specification Supersedes data of 1999 Apr 26 2001 Oct 26





### NPN/PNP general purpose transistor

#### **BC847BPN**

#### **FEATURES**

- Low collector capacitance
- Low collector-emitter saturation voltage
- Closely matched current gain
- Reduces number of components and boardspace
- No mutual interference between the transistors.

#### **APPLICATIONS**

• General purpose switching and amplification.

#### **DESCRIPTION**

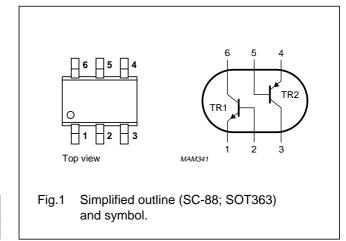
NPN/PNP transistor pair in an SC-88; SOT363 plastic package.

#### **MARKING**

TYPE NUMBER	MARKING CODE
BC847BPN	13t

#### **PINNING**

PIN	DESCRIPTION		
1, 4	emitter	TR1; TR2	
2, 5	base	TR1; TR2	
6, 3	collector	TR1; TR2	



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT	
Per transist	Per transistor; for the PNP transistor with negative polarity					
V <sub>CBO</sub>	collector-base voltage	open emitter	_	50	V	
V <sub>CEO</sub>	collector-emitter voltage	open base	_	45	V	
V <sub>EBO</sub>	emitter-base voltage	open collector	_	5	V	
I <sub>C</sub>	collector current (DC)		_	100	mA	
I <sub>CM</sub>	peak collector current		_	200	mA	
I <sub>BM</sub>	peak base current		_	200	mA	
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	_	200	mW	
T <sub>stg</sub>	storage temperature		-65	+150	°C	
Tj	junction temperature		_	150	°C	
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C	
Per device			•	•	•	
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	300	mW	

#### Note

1. Device mounted on an FR4 printed-circuit board.

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#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
Per device				
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	416	K/W

#### Note

1. Device mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

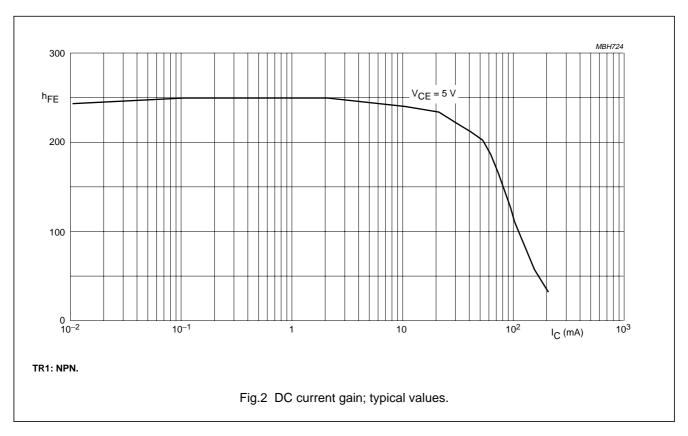
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Per transistor unless otherwise specified; for the PNP transistor with negative polarity						
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = 30 V	_	_	15	nA
		I <sub>E</sub> = 0; V <sub>CB</sub> = 30 V; T <sub>j</sub> = 150 °C	_	_	5	μΑ
I <sub>EBO</sub>	emitter cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = 5 V	_	_	100	nA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> = 2 mA; V <sub>CE</sub> = 5 V	200	_	450	
V <sub>CEsat</sub>	collector-emitter saturation	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA	_	_	100	mV
	voltage	I <sub>C</sub> = 100 mA; I <sub>B</sub> = 5 mA; note 1	_	_	300	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA	_	755	_	mV
V <sub>BE</sub>	base-emitter voltage	I <sub>C</sub> = 2 mA; V <sub>CE</sub> = 5 V				
	TR1 NPN		580	655	700	mV
	TR2 PNP		600	655	750	mV
C <sub>c</sub>	collector capacitance	I <sub>E</sub> = i <sub>e</sub> = 0; V <sub>CB</sub> = 10 V; f = 1 MHz				
	TR1 NPN		_	_	1.5	pF
	TR2 PNP		_	_	2.2	pF
C <sub>e</sub>	emitter capacitance	$I_C = i_c = 0$ ; $V_{EB} = 500 \text{ mV}$ ; $f = 1 \text{ MHz}$				
	TR1 NPN		_	11	_	pF
	TR2 PNP		_	10	_	pF
f <sub>T</sub>	transition frequency	I <sub>C</sub> = 10 mA; V <sub>CE</sub> = 5 V; f = 100 MHz	100	_	-	MHz

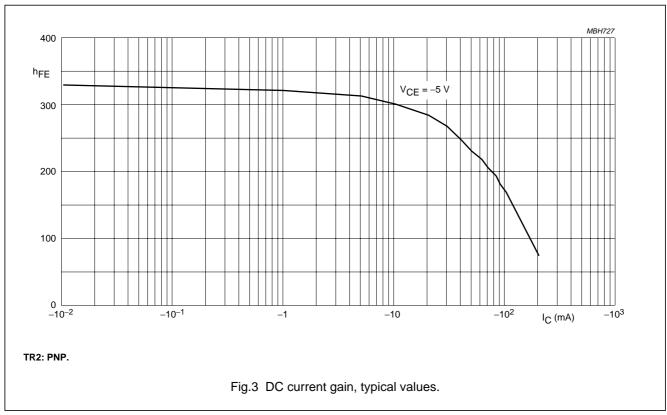
#### Note

1. Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

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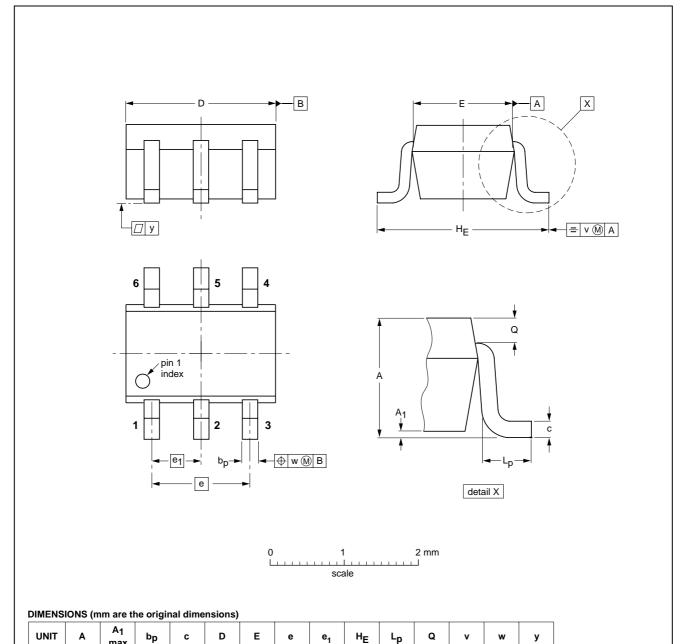
# NPN/PNP general purpose transistor

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#### **PACKAGE OUTLINE**

Plastic surface mounted package; 6 leads

**SOT363** 



OUTLINE		REFERENCES		EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT363			SC-88			97-02-28

0.65

0.45 0.15 0.25 0.15

0.2

0.1

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0.25 0.10 2.2 1.8 1.35 1.15

1.3

0.30

0.20

1.1 0.8

mm

0.1

#### NPN/PNP general purpose transistor

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DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
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# NPN/PNP general purpose transistor

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